BD237G (NPN), BD234G, BD238G (PNP)

Plastic Medium Power Bipolar Transistors

Designed for use in 5.0 to 10 W audio amplifiers and drivers utilizing complementary or quasi complementary circuits.

Features

- High DC Current Gain
- Epoxy Meets UL 94 V0 @ 0.125 in
- These Devices are Pb-Free and are RoHS Compliant*

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Collector–Emitter Voltage BD234G DB237G, BD238G	V _{CEO}	45 80	Vdc
Collector–Base Voltage BD234G DB237G, BD238G	V _{CBO}	60 100	Vdc
Emitter-Base Voltage	V _{EBO}	5.0	Vdc
Collector Current	Ι _C	2.0	Adc
Base Current	Ι _Β	1.0	Adc
Total Device Dissipation @ $T_C = 25^{\circ}C$	P _D	25	W
Operating and Storage Junction Temperature Range	T _J , T _{stg}	-55 to +150	°C
ESD – Human Body Model	HBM	3B	V
ESD – Machine Model	MM	С	V

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

THERMAL CHARACTERISTICS

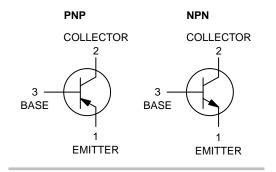
Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction-to-Case	R_{\thetaJC}	5.0	°C/W



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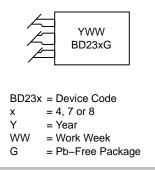
http://onsemi.com

2.0 AMPERES POWER TRANSISTORS 25 WATTS





MARKING DIAGRAM



ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 4 of this data sheet.

*For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

BD237G (NPN), BD234G, BD238G (PNP)

Characteristic	Symbol	Min	Max	Unit
Collector–Emitter Sustaining Voltage (Note 1) ($I_C = 0.1$ Adc, $I_B = 0$) BD237G, BD238G BD234G	V _{(BR)CEO}	80 45	-	Vdc
Collector Cutoff Current $(V_{CB} = 100 \text{ Vdc}, I_E = 0)$ BD237G, BD238G $(V_{CB} = 60 \text{ Vdc}, I_F = 0)$	Ісво	-	0.1	mAdc
BD234G		-	0.1	
Emitter Cutoff Current ($V_{BE} = 5.0 \text{ Vdc}, I_C = 0$)	I _{EBO}	_	1.0	mAdc
DC Current Gain ($I_C = 0.15 \text{ A}, V_{CE} = 2.0 \text{ V}$) ($I_C = 1.0 \text{ A}, V_{CE} = 2.0 \text{ V}$)	h _{FE1} h _{FE2}	40 25		-
Collector–Emitter Saturation Voltage (Note 1) ($I_C = 1.0 \text{ Adc}, I_B = 0.1 \text{ Adc}$)	V _{CE(sat)}	_	0.6	Vdc
Base-Emitter On Voltage (Note 1) (I _C = 1.0 Adc, V _{CE} = 2.0 Vdc)	V _{BE(on)}	_	1.3	Vdc
Current–Gain – Bandwidth Product ($I_C = 250 \text{ mAdc}, V_{CE} = 10 \text{ Vdc}, f = 1.0 \text{ MHz}$)	f _T	3.0	_	MHz

ELECTRICAL CHARACTERISTICS (T_C = 25°C unless otherwise noted)

1. Pulse Test: Pulse Width \leq 300 μ s, Duty Cycle \leq 2.0%.

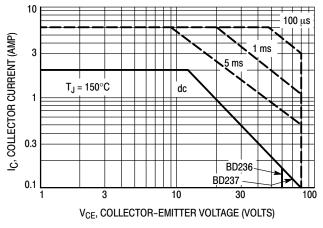
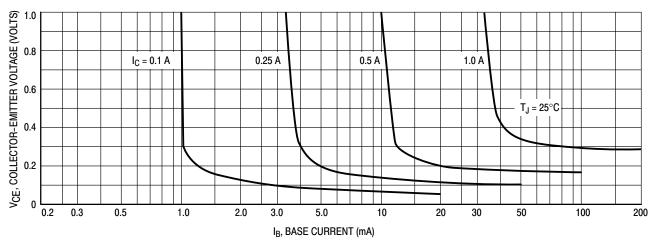


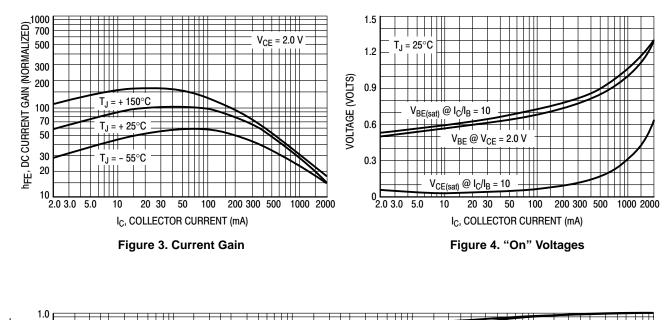
Figure 1. Active Region Safe Operating Area

The Safe Operating Area Curves indicate $I_{C-}V_{CE}$ limits below which the device will not enter secondary breakdown. Collector load lines for specific circuits must fall within the applicable Safe Area to avoid causing a catastrophic failure. To insure operation below the maximum T_J , power-temperature derating must be observed for both steady state and pulse power conditions.

BD237G (NPN), BD234G, BD238G (PNP)







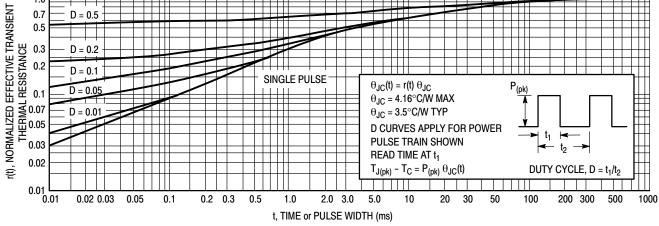


Figure 5. Thermal Response

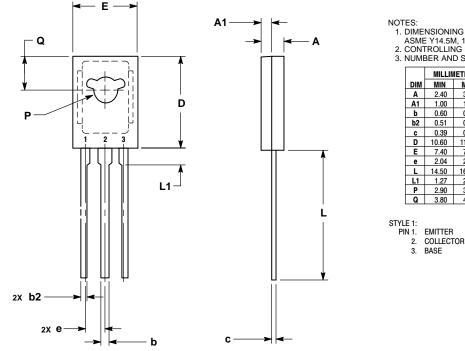
BD237G (NPN), BD234G, BD238G (PNP)

ORDERING INFORMATION

Device	Package	Shipping
BD234G	TO–225 (Pb–Free)	500 Units / Box
BD237G	TO-225 (Pb-Free)	500 Units / Box
BD238G	TO-225 (Pb-Free)	500 Units / Box

PACKAGE DIMENSIONS





1. DIMENSIONING AND TOLERANCING PER

ASME Y14.5M, 1994. CONTROLLING DIMENSION: MILLIMETERS. 3. NUMBER AND SHAPE OF LUGS OPTIONAL.

	MILLIMETERS		
DIM	MIN	MAX	
Α	2.40	3.00	
A1	1.00	1.50	
b	0.60	0.90	
b2	0.51	0.88	
C	0.39	0.63	
D	10.60	11.10	
Е	7.40	7.80	
е	2.04	2.54	
L	14.50	16.63	
L1	1.27	2.54	
Р	2.90	3.30	
Q	3.80	4.20	

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